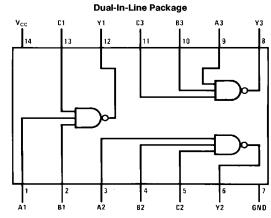
June 1989

DM54L10 Triple 3-Input NAND Gates

General Description

This device contains three independent gates each of which performs the logic NAND function.

Connection Diagram



Order Number DM54L10J or DM54L10W See NS Package Number J14A or W14B TL/F/6619-1

Function Table

 $Y = \overline{ABC}$

Inputs			Output
Α	В	С	Υ
Х	Х	L	Н
x	L	X X	Н
L	×	X	Н
н	Н	н	L

H = High Logic Level

L = Low Logic Level

X = Either Low or High Logic Level

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Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 8V Input Voltage 5.5V

Operating Free Air Temperature Range

DM54L -55°C to +125°C Storage Temperature Range -65°C to +150°C Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter		Units		
		Min	Nom	Max	Oilles
V _{CC}	Supply Voltage	4.5	5	5.5	V
V _{IH}	High Level Input Voltage	2			V
V _{IL}	Low Level Input Voltage			0.7	V
ГОН	High Level Output Current			-0.2	mA
l _{OL}	Low Level Output Current			2	mA
T _A	Free Air Operating Temperature	-55		125	°C

Electrical Characteristics over recommended operating free air temperature (unless otherwise noted)

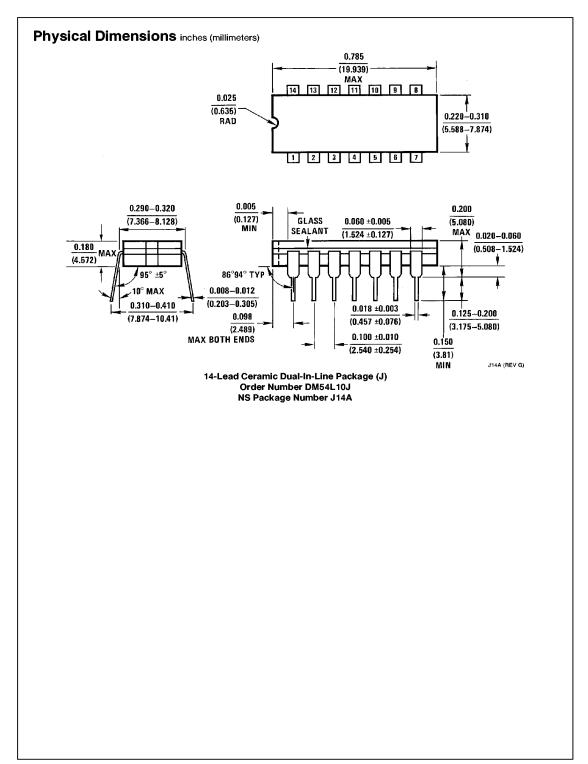
Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units
Voн	High Level Output Voltage	$V_{CC} = Min, I_{OH} = Max$ $V_{IL} = Max$	2.4	3.3		٧
V _{OL}	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min$		0.15	0.3	٧
lį	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$			0.1	mA
lін	High Level Input Current	$V_{CC} = Max, V_I = 2.4V$			10	μΑ
I _{IL}	Low Level Input Current	$V_{CC} = Max, V_I = 0.3V$			-0.18	mA
los	Short Circuit Output Current	V _{CC} = Max (Note 2)	-3		-15	mA
Іссн	Supply Current with Outputs High	V _{CC} = Max		0.33	0.6	mA
ICCL	Supply Current with Outputs Low	V _{CC} = Max		0.87	1.53	mA

$\textbf{Switching Characteristics} \text{ at V}_{CC} = 5 \text{V and T}_{A} = 25^{\circ}\text{C (See Section 1 for Test Waveforms and Output Load)}$

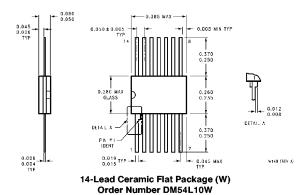
Symbol	Parameter	Conditions	Min	Max	Units
^t PLH	Propagation Delay Time Low to High Level Output	$R_L = 4 k\Omega,$ $C_L = 50 pF$		60	ns
^t PHL	Propagation Delay Time High to Low Level Output			60	ns

Note 1: All typicals are at $V_{\rm CC} = 5V$, $T_{\rm A} = 25^{\circ}{\rm C}$.

Note 2: Not more than one output should be shorted at a time.



Physical Dimensions inches (millimeters) (Continued)



NS Package Number W14B

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